

Vishay High Power Products

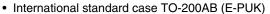
Phase Control Thyristors (Hockey PUK Version), 960 A



TO-200AB (E-PUK)

FEATURES

- · Center amplifying gate
- · Metal case with ceramic insulator





- Extended temperature range
- Low profile hockey PUK to increase current-carrying capability
- Lead (Pb)-free
- · Designed and qualified for industrial level

PRODUCT SUMMARY				
I _{T(AV)}	960 A			

TYPICAL APPLICATIONS

- · DC motor controls
- · Controlled DC power supplies
- · AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
1		960	A			
I _{T(AV)}	T _{hs}	80	°C			
		2220	А			
I _{T(RMS)}	T _{hs}	25	°C			
I _{TSM}	50 Hz	12 500	Δ.			
	60 Hz	13 000	Α			
l ² t	50 Hz	782	1.42-			
	60 Hz	713	kA ² s			
V _{DRM} /V _{RRM}		400 to 600	V			
tq	Typical	100	μs			
T _J		- 40 to 150	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA					
ST380CHC	04	400	500	100					
010000110	06	600	700	100					

ST380CHPbF Series

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ABSOLUTE MAXIMUM RATIN	GS					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current		180° condu	180° conduction, half sine wave			Α
at heatsink temperature	I _{T(AV)}	double side	double side (single side) cooled			°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink tempe	erature double side cooled	2220	
		t = 10 ms	No voltage		12 500	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		13 000	A kA ² s
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}	Sinusoidal half wave, initial $T_J = T_J$ maximum	10 500	
		t = 8.3 ms	reapplied		11 000	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage reapplied		782	
		t = 8.3 ms			713	
		t = 10 ms			553	
		t = 8.3 ms	reapplied		505	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10	t = 0.1 to 10 ms, no voltage reapplied			kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum			V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.88	V
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x I _{T(AV)} < I < π x I _{T(AV)}), T _J = T _J maximum			0.25	m 0
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.24	mΩ
Maximum on-state voltage	V_{TM}	$I_{pk} = 2900 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.58	V
Maximum holding current	I _H	T 05 00 and a small 40 V maintain I			600	m A
Typical latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000	- mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%$ V_{DRM}	1000	A/µs
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1$ A/ μ s $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.0	
Typical turn-off time	t _q	$I_{TM} = 550 \text{ A, } T_J = T_J \text{ maximum, dI/dt} = 40 \text{ A/}\mu\text{s,}$ $V_R = 50 \text{ V, dV/dt} = 20 \text{ V/}\mu\text{s, gate 0 V } 100 \Omega, t_p = 500 \mu\text{s}$	100	μs

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs		
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	100	mA		





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TRIGGERING						
DADAMETED	CVMDOL	TEGT COMPLETIONS			VALUES	
PARAMETER	SYMBOL	I E	ST CONDITIONS	TYP.	MAX.	UNITS
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10.0		W
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	$t_p \leq 5 \text{ ms}$	3	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	T - T maximum	+ < 5 ma	20		V
Maximum peak negative gate voltage	- V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms			5.0	
	I _{GT}	T _J = - 40 °C	Maximum required gate trigger/ current/voltage are the lowest value which will trigger all units	200	-	
DC gate current required to trigger		T _J = 25 °C		100	200	mA
		T _J = 150 °C		40	-	
		T _J = - 40 °C		2.5	-	
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	V
		T _J = 150 °C		1.0	-	
DC gate current not to trigger	I _{GD}	T - T maximum	Maximum gate current/voltage not to trigger is the maximum	10		mA
DC gate voltage not to trigger	V_{GD}	$T_J = T_J \text{ maximum}$	value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.25		V

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction temperature range	T_J		- 40 to 150	°C		
Maximum storage temperature range	T_{Stg}					
Maximum thermal registence, junction to heateink	D	DC operation single side cooled 0.				
Maximum thermal resistance, junction to heatsink	R _{thJ-hs}	DC operation double side cooled	0.04	K/W		
Maximum thermal registance, each to heataink	R _{thC-hs}	DC operation single side cooled	0.02	IV/VV		
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.01			
Mounting force, ± 10 %			9800 (1000)	N (kg)		
Approximate weight			83	g		
Case style		See dimensions - link at the end of datasheet	TO-200AB (E	E-PUK)		

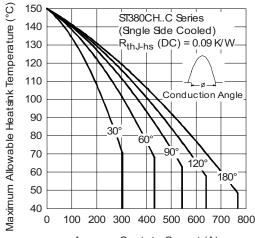
△R _{thJ-hs} CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS	
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS	
180°	0.010	0.011	0.007	0.007	$T_J = T_J$ maximum	K/W	
120°	0.012	0.012	0.012	0.013			
90°	0.015	0.015	0.016	0.017			
60°	0.022	0.022	0.023	0.023			
30°	0.036	0.036	0.036	0.037			

Note

• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

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Average On-state Current (A)
Fig. 1 - Current Ratings Characteristics

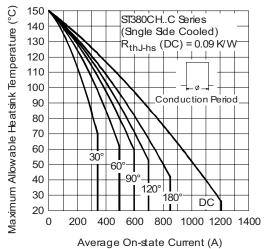
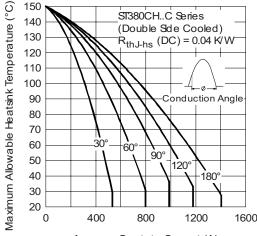


Fig. 2 - Current Ratings Characteristics



Average On-state Current (A)
Fig. 3 - Current Ratings Characteristics

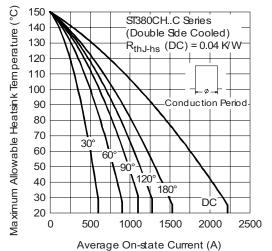
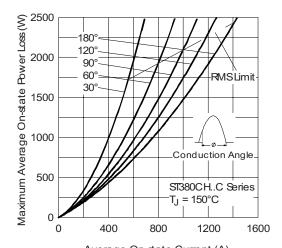


Fig. 4 - Current Ratings Characteristics



Average On-state Current (A) Fig. 5 - On-State Power Loss Characteristics

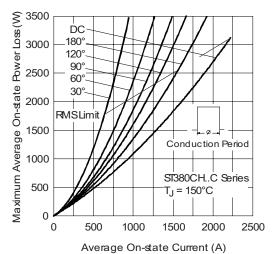


Fig. 6 - On-State Power Loss Characteristics



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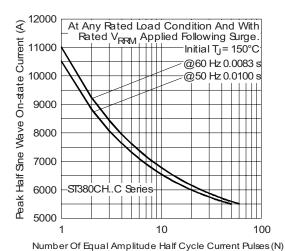


Fig. 7 - Maximum Non-Repetitive Surge Current

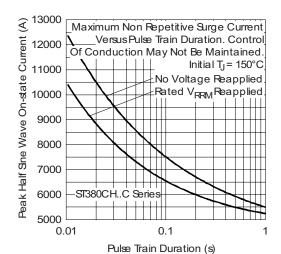
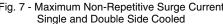


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled



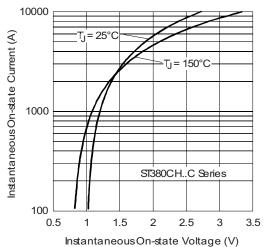


Fig. 9 - On-State Voltage Drop Characteristics

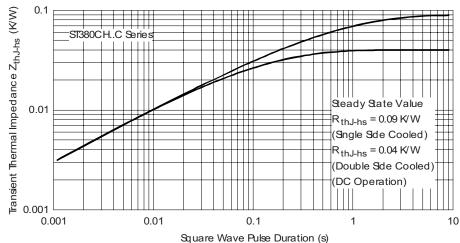


Fig. 10 - Thermal Impedance ZthJ-hs Characteristics

ST380CHPbF Series

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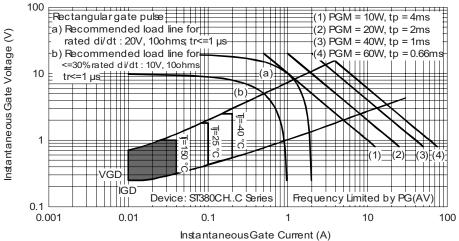
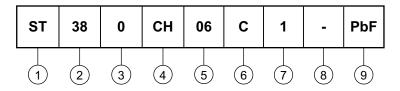


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



- 1 Thyristor
- 2 Essential part number
- 3 0 = Converter grade
- 4 CH = Ceramic PUK, high temperature
- 5 Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 6 C = PUK case TO-200AB (E-PUK)
- 7 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)
 - 1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)
 - 2 = Eyelet terminals (gate and auxiliary cathode soldered leads)
 - 3 = Fast-on terminals (gate and auxiliary cathode soldered leads)
- Critical dV/dt:
 • None = 500 V/µs (standard selection)
 - L = 1000 V/µs (special selection)
- 9 Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95075			

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